HALOGEN

FREE



Low-Voltage, Low Ron Quad SPST Analog Switch

DESCRIPTION

The DG2041/2042/2043 are quad single-pole/single-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, fast switching, low on-resistance ($R_{DS(on)}$: 1 Ω at 2.7 V) and small physical size, the DG2041/2042/2043 are ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2041/2042/2043 are built on Vishay Siliconix's new high density low voltage process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FEATURES

- Low Voltage Operation (1.8 V to 5.5 V)
- Low On-Resistance $R_{DS(on)}$: 1 Ω
- Fast Switching 14 ns toN
- Low Charge Injection Q_{IN.I}: 1 pC
- Low Power Consumption
- TTL/CMOS Compatible
- TSSOP-16 and QFN-16 Packages
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

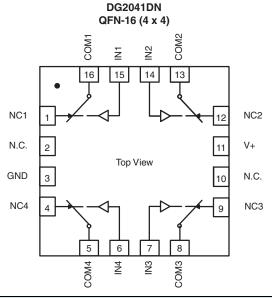
BENEFITS

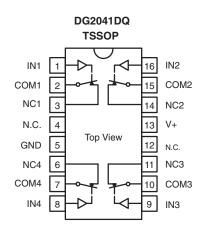
- **Reduced Power Consumption**
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

APPLICATIONS

- Cellular Phones
- Communication Systems
- Portable Test Equipment
- **Battery Operated Systems**
- Sample and Hold Circuits

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION - DG2041





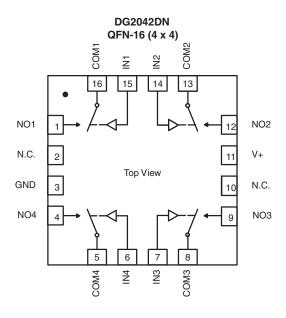
TRUTH TABLE - DG2041	
Logic	Switch
0	On
1	Off

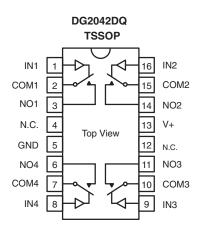
Switches Shown for Logic "0" Input

Document Number: 72091 S13-1285-Rev. C, 27-May-13 For technical questions, contact: pmostechsupport@vishay.com



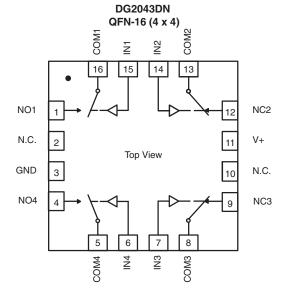
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION - DG2042, DG2043

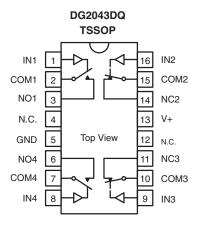




TRUTH TABLE - DG2042	
Logic	Switch
0	Off
1	On

Switches Shown for Logic "0" Input





TRUTH TABLE - DG2043		
Logic	Switches 1, 4	Switches 2, 3
0	Off	On
1	On	Off

Switches Shown for Logic"0" Input



ORDERING INFORMATION									
Temp Range	Package	Part Number							
		DG2041DQ-T1							
		DG2041DQ-T1-E3							
	TSSOP-16	DG2042DQ-T1							
	1330F-16	DG2042DQ-T1-E3							
- 40 °C to 85 °C		DG2043DQ-T1							
		DG2043DQ-T1-E3							
	OFN 40 (4 mm - 4 mm)	DG2041DN-T1-E4							
	QFN-16 (4 mm x 4 mm) (Variation 1)	DG2042DN-T1-E4							
	(vanadon 1)	DG2043DN-T1-E4							

ABSOLUTE MAXIMUM RATINGS										
Parameter		Symbol	Limit	Unit						
Reference V+ to GND			- 0.3 to + 6	V						
IN, COM, NC, NO ^a			- 0.3 to (V+ + 0.3)	7 v						
Continuous Current (Any terminal)			± 50	mA						
Peak Current (Pulsed at 1 ms, 10 % d	uty cycle)		± 200	- IIIA						
Storage Temperature (D Suffix)			- 65 to 150	°C						
Develop Dissipation (Declares)	TSSOP-16 ^c		450	mW						
Power Dissipation (Packages) ^b	QFN-16 (4 mm x 4 mm) ^d		1880	11100						

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 5.6 mW/°C above 70 °C
- d. Derate 23.5 mW/°C above 70 °C
- e. Manual soldering with soldering iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

SPECIFICATIONS (V+ = 2 V)											
		Test Conditions Otherwise Unless Specified		- 40							
Parameter	Symbol	$V+ = 2 V$, $V_{IN} = 0.4 V$ or 1.6 V^e	Temp.a	Min.b	Typ.c	Max.b	Unit				
Analog Switch											
Analog Signal Range ^d	$V_{NO}, V_{NC} V_{COM}$		Full	0		V+	V				
On- Resistance	R _{ON}	V+ = 2 V, V _{COM} = 0.2 V/1.2 V, I _{NO} , I _{NC} = 10 mA	Room Full		3	6.3 6.3					
R _{ON} Flatness ^d	R _{ON} Flatness	$V+ = 2 V$, $V_{COM} = 0 V$ to $V+$, I_{NO} , $I_{NC} = 10 \text{ mA}$	Room			4.2	Ω				
R _{ON} Match Between Channels	ΔR_{ON}		Room			0.4					
Cuitab Off Lastrage Command	I _{NO(off)} I _{NC(off)}	V+ = 2.2 V	Room Full ^d	- 1 - 10		1 10					
Switch Off Leakage Current ^I	I _{COM(off)}	V_{NO} , $V_{NC} = 0.2 \text{ V/2 V}$, $V_{COM} = 2 \text{ V/0.2 V}$	Room Full ^d	- 1 - 10		1 10	nA				
Channel-On Leakage Current ^f	I _{COM(on)}	$V+ = 2.2 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.2 \text{ V/2 V}$	Room Full ^d	- 1 - 10		1 10					

DG2041, DG2042, DG2043

Vishay Siliconix



SPECIFICATIONS (V+ = 2 V)										
		Test Conditions Otherwise Unless Specified		- 40						
Parameter	Symbol	$V+ = 2 V$, $V_{IN} = 0.4 V$ or 1.6 V^e	Temp.a	Min.b	Typ.c	Max.b	Unit			
Digital Control										
Input High Voltage	V_{INH}		Full	1.6			V			
Input Low Voltage	V_{INL}		Full			0.4	V			
Input Capacitance ^d	C _{in}		Full		4		pF			
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 V or V+	Full	- 1		1	μΑ			
Dynamic Characteristics										
Turn-On Time	t _{ON}	V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω , C_L = 35 pF	Room Full ^d		30	81 82				
Turn-Off Time	t _{OFF}	fig. 1 and 2	Room Full ^d		22	41 42	ns			
Break-Before-Make Time Delay	t _D	V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω , C_L = 35 pF (DG2043 Only)	Room	5						
Charge Injection ^d	Q _{INJ}	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega, \text{ fig. 2}$	Room		1		рC			
Off-Isolation ^d	OIRR	D 5000 5 7 1 1 MHz	Room		- 63		-10			
Crosstalk ^d	X _{TALK}	$R_L = 50 \Omega$, $C_L = 5 pF$, $f = 1 MHz$	Room		- 95		dB			
NO, NC Off Capacitance ^d	$C_{NO(off)} \ C_{NC(off)}$	V _{IN} = 0 V or V+, f = 1 MHz	Room		24		pF			
Channel-On Capacitanced	C _{ON}		Room		48					
Power Supply										
Power Supply Current ^d	l+	$V_{IN} = 0 V \text{ or } V+$			0.001	1	μΑ			

SPECIFICATIONS (V+ = 3 V)										
		Test Conditions Otherwise Unless Specified			Limits - 40 to 85 °C					
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.4 V \text{ or } 2 V^{e}$	Temp.a	Min.b	Typ. ^c	Max.b	Unit			
Analog Switch										
Analog Signal Range ^d	$V_{NO}, V_{NC} V_{COM}$		Full	0		V+	٧			
On-Resistance	R _{ON}	$V+ = 2.7 \text{ V}, V_{COM} = 0.7 \text{ V}/1.5 \text{ V}, I_{NO},$ $I_{NC} = 10 \text{ mA}$	Room Full		1.6	2.1 2.2				
R _{ON} Flatness ^d	R _{ON} Flatness	V+ = 2.7 V, V _{COM} = 0 V to V+, I _{NO} , I _{NC} = 10 mA	Room			0.7	Ω			
R _{ON} Match Between Channels	ΔR_{ON}		Room			0.3				
Switch Off Leakage Current ^f	I _{NO(off)} I _{NC(off)}	V+ = 3.3 V	Room Full	- 1 - 10		1 10				
Owner on Leakage ourrent	I _{COM(off)}	V_{NO} , $V_{NC} = 0.3 \text{ V/3 V}$, $V_{COM} = 3 \text{ V/0.3 V}$	Room Full	- 1 - 10		1 10	nA			
Channel-On Leakage Current ^f	I _{COM(on)}	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V/3 V}$	Room Full	- 1 - 10 10						
Digital Control										
Input High Voltage ^d	V_{INH}		Full	1.6			V			
Input Low Voltage V _I			Full			0.4	, v			
Input Capacitance ^d	C _{in}		Full		4		pF			
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 V or V+	Full	- 1		1	μΑ			



SPECIFICATIONS (V+ = 3 V)										
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C						
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.4 V \text{ or } 2 V^{e}$	Temp.a	Min. ^b	Typ. ^c	Max. ^b	Unit			
Dynamic Characteristics										
Turn-On Time ^d	t_{ON}	V_{NO} or $V_{NC} = 2 \text{ V}$, $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$	Room Full		19	51 52				
Turn-Off Time ^d	t _{OFF}	fig. 1 and 2	Room Full		17	36 37	ns			
Break-Before-Make Time Delay	t _D	V_{NO} or V_{NC} = 2 V, R_{L} = 300 Ω , C_{L} = 35 pF (DG2043 Only)	Room	2						
Charge Injection ^d	Q_{INJ}	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ Ω , fig. 2	Room		3		рC			
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room		- 63		dB			
Crosstalk ^d	X _{TALK}	11[= 30 32, 0[= 3 μι, τ = 1 ινιτι2	Room		- 94		ub			
NO, NC Off Capacitance ^d	$C_{NO(off)} \ C_{NC(off)}$	V _{IN} = 0 V or V+, f = 1 MHz	Room		25		pF			
Channel-On Capacitance ^d C _{ON}			Room		49					
Power Supply										
Power Supply Current	l+	$V_{IN} = 0 V \text{ or } V+$			0.001	1	μΑ			

SPECIFICATIONS (V+ = 5 V)										
		Test Conditions Otherwise Unless Specified		- 40						
Parameter	Symbol	$V+ = 5 V$, $\pm 10 \%$, $V_{IN} = 0.8 V$ or 2.4 V^e	Temp.a	Min.b	Typ. ^c	Max. ^b	Unit			
Analog Switch										
Analog Signal Range ^d	$V_{NO}, V_{NC} \ V_{COM}$		Full	0		V+	V			
On-Resistance	R_{ON}	$V+ = 4.5 \text{ V}, V_{COM} = 0.7 \text{ V}/2.5 \text{ V}, I_{NO},$ $I_{NC} = 10 \text{ mA}$	Room Full		1	1.5 1.6				
R _{ON} Flatness ^d	R _{ON} Flatness	$V+ = 4.5 \text{ V}, V_{COM} = 0 \text{ V to V}+, I_{NO}, I_{NC} = 10 \text{ mA}$	Room			0.7	Ω			
R _{ON} Match Between Channels	ΔR_{ON}	V+ = 4.5 V, VCOM = 0 V to V+, INO, INC = 10 IIIA	Room			0.3				
Switch Off Leakage Current	$I_{NO(off)}$ $I_{NC(off)}$	V+ = 5.5 V	Room Full	- 1 - 10		1 10				
Owner on Lounage out on	I _{COM(off)}	V _{NO} , V _{NC} = 1 V/4.5 V, V _{COM} = 4.5 V/1 V	Room Full	- 1 - 10		1 10	nA			
Channel-On Leakage Current	I _{COM(on)}	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 1 \text{ V}/4.5 \text{ V}$	Room Full	- 1 - 10		1 10				
Digital Control										
Input High Voltage	V_{INH}		Full	2.4			V			
Input Low Voltage	V _{INL}		Full			0.8				
Input Capacitance	C _{in}		Full		4		pF			
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 V or V+	Full	- 1		1	μΑ			



SPECIFICATIONS (V+ = 5 V)											
		Test Conditions Otherwise Unless Specified			Limits - 40 °C to 85 °C						
Parameter	Symbol	$V+ = 5 V$, $\pm 10 \%$, $V_{IN} = 0.8 V$ or 2.4 V^e	Temp.a	Min. ^b	Typ. ^c	Max. ^b	Unit				
Dynamic Characteristics											
Turn-On Time ^d	t _{ON}	V_{NO} or V_{NC} = 3 V, R_L = 300 Ω , C_L = 35 pF	Room Full		13	42 43					
Turn-Off Time ^d	t _{OFF}	fig. 1 and 2	Room Full		19	32 33	ns				
Break-Before-Make Time Delay	t _D	V_{NO} or V_{NC} = 3 V, R_L = 300 Ω , C_L = 35 pF (DG2043 Only)	Room	1							
Charge Injection ^d	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, R_{GEN} = 0 Ω , fig. 2	Room		3		рС				
Off-Isolation ^d	OIRR	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room		- 63		dB				
Crosstalk ^d	X _{TALK}	11 = 30 32, 0 = 3 β1, 1 = 1 101112	Room		- 93		ub				
Source-Off Capacitance ^d	C _{NO(off)} C _{NC(off)}	V _{IN} = 0 V or V+, f = 1 MHz	Room		26		pF				
Channel-On Capacitance ^d	C _{ON}		Room		49						
Power Supply											
Power Supply Current	l+	$V_{IN} = 0 V \text{ or } V+$			0.001	1	μΑ				

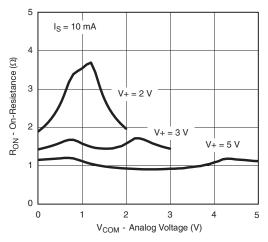
Notes:

- a. Room = 25 °C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by 5 V leakage testing, not production tested.

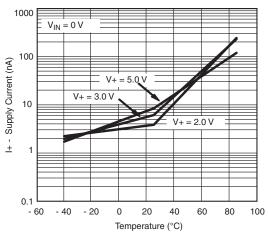
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



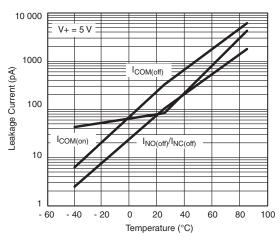
TYPICAL CHARACTERISTICS (25 °C unless noted)



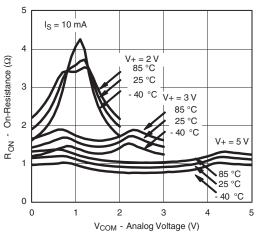
 R_{ON} vs. V_{COM} and Supply Voltage



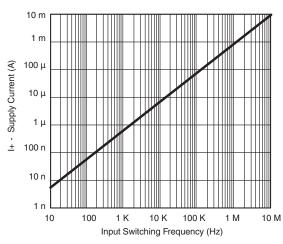
Supply Current vs. Temperature



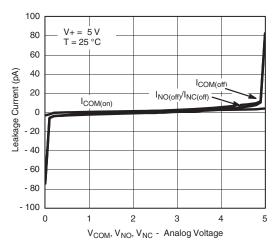
Leakage Current vs. Temperature



R_{ON} vs. Analog Voltage and Temperature



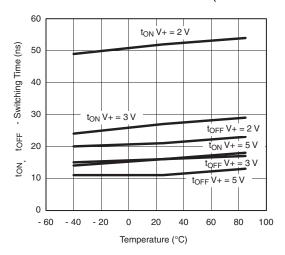
Supply Current vs. Input Switching Frequency



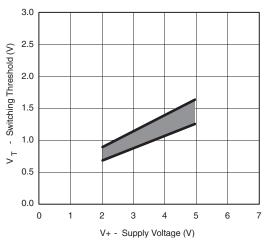
Leakage vs. Analog Voltage

TYPICAL CHARACTERISTICS (25 °C unless noted)

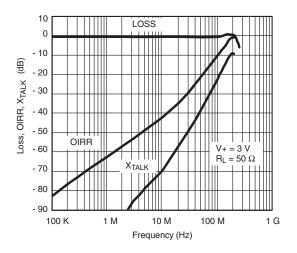




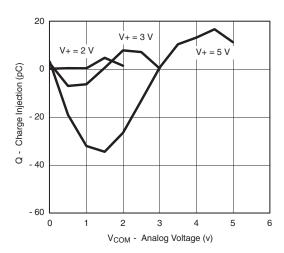
Switching Time vs. Temperature and Supply Voltage



Switching Threshold vs. Supply Voltage



Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage

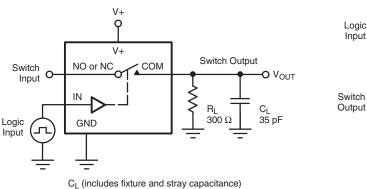
< 5 ns

< 5 ns

0.9 x V_{OUT}



TEST CIRCUITS



Logic "1" = Switch On

 t_{ON}

 V_{INH}

 V_{INL}

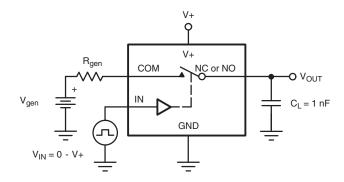
0 V

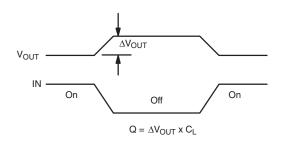
Logic input waveforms inverted for switches that have the opposite logic sense.

50 %

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

Figure 1. Switching Time





IN depends on switch configuration: input polarity determined by sense of switch.

Figure 2. Charge Injection

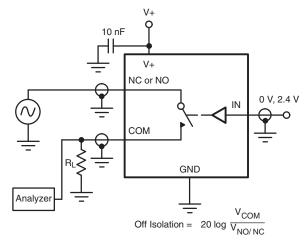


Figure 3. Off-Isolation

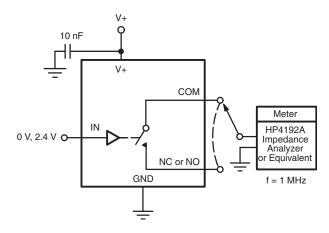
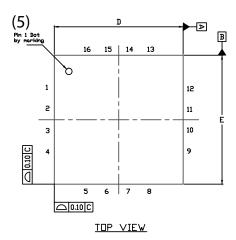


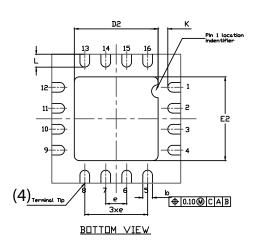
Figure 4. Channel Off/On Capacitance

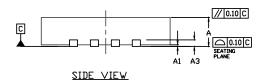
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72091.



QFN 4x4-16L Case Outline







			VAR	IATION 1			VARIATION 2						
DIM	МІ	MILLIMETERS ⁽¹⁾			INCHES		MILLIMETERS ⁽¹⁾		S ⁽¹⁾		INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037	
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
A3		0.20 ref.			0.008 ref.			0.20 ref.			0.008 ref.		
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.010 0.012 0.		
D	4.00 BSC		0	0.157 BSC		4.00 BSC			0.157 BSC				
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
е		0.65 BS0)		0.026 BSC		0.65 BSC				0.026 BSC		
Е		4.00 BS0	0		0.157 BSC		4.00 BSC				0.157 BSC		
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
K		0.20 min.			0.008 min.			0.20 min.			0.008 min.		
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020	
N ⁽³⁾		16			16		6 16			16			
Nd ⁽³⁾		4			4			4			4		
Ne ⁽³⁾		4			4			4			4		

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

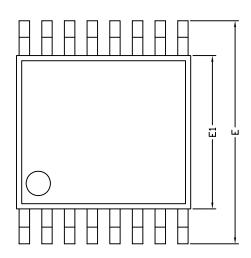
ECN: S13-0893-Rev. B, 22-Apr-13

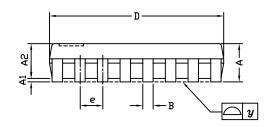
DWG: 5890

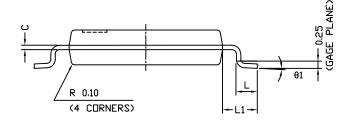
Revision: 22-Apr-13



TSSOP: 16-LEAD







	DIMENSIONS IN MILLIMETERS		
Symbols	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
В	0.22	0.28	0.38
С	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	-	-	0.10
θ1	0°	3°	6°
FCN: S-61920-Bev D 23-	Oct-06		

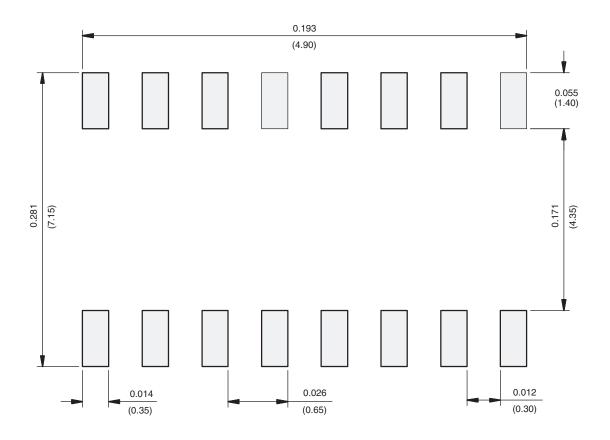
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23-Oct-06
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RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



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